

SEMITOP®3

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter **SK 30 DGDL 066 ET** 

**Target Data** 

#### **Features**

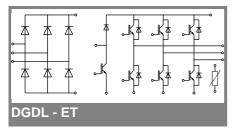
- Compact design
- · One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench IGBT technology
- · CAL technology FWD
- Integrated NTC temperature sensor

#### **Typical Applications**

- Inverter up to 10 kVA
- Typ. motor power 4 kW

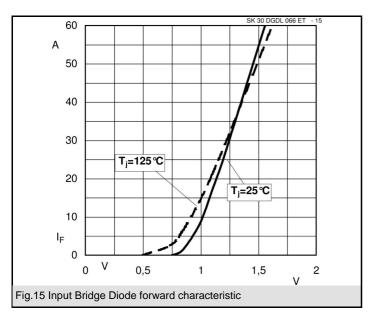
#### Remarks

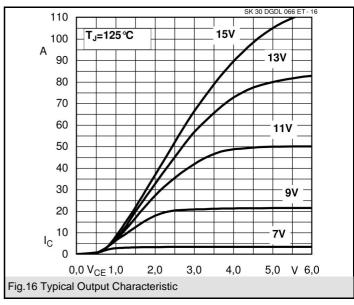
• V<sub>CE,sat</sub> , V<sub>F</sub> = chip level value

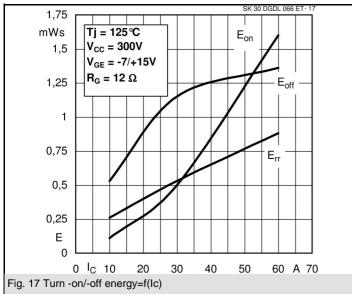


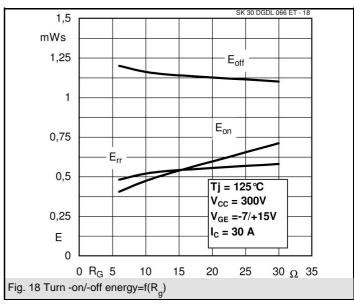
<b>Absolute Maximum Ratings</b> $T_s = 25^{\circ}C$ , unless otherwise specified								
Symbol	Conditions	Values	Units					
IGBT - Inverter, chopper								
V <sub>CES</sub>	T <sub>s</sub> = 25 (70) °C, T <sub>j</sub> = 175 °C	600 38 (31)	V A					
I <sub>C</sub> I <sub>CRM</sub> V <sub>GES</sub>	$T_s = 25 (70) ^{\circ}C, T_j = 150 ^{\circ}C$ $I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$	35 (26) 60 ± 20	A A V					
T <sub>j</sub>		-40 <b>+</b> 175	°C					
Diode - Inverter, chopper								
I <sub>F</sub>	$T_s = 25 (70) ^{\circ}C, T_i = 150 ^{\circ}C$	32 (24)	Α					
I <sub>F</sub>	$T_s = 25 (70) ^{\circ}C, T_j = 175 ^{\circ}C$	36 (28)	Α					
I <sub>FRM</sub>	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$	60	Α					
Diode - Rectifier								
$V_{RRM}$		800	V					
I <sub>F</sub>	$T_s = 70 ^{\circ}\text{C}$	35	Α					
I <sub>FSM</sub>	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_j = 25 ^\circ\text{C}$	370	Α					
i²t	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_j = 25 ^\circ\text{C}$	680	A²s					
T <sub>j</sub>		-40 + 175	°C					
T <sub>sol</sub>	Terminals, 10 s	260	°C					
T <sub>stg</sub>		-40 <b>+</b> 125	°C					
V <sub>isol</sub>	AC, 1 min.	2500	V					

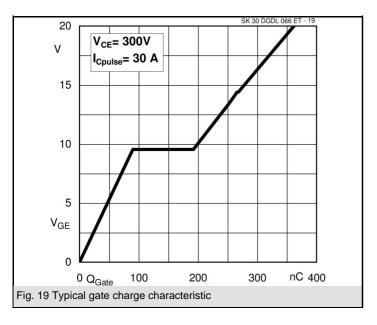
Characteristics		T <sub>s</sub> = 25°C	T <sub>s</sub> = 25°C , unless otherwise specified					
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter, chopper								
V <sub>CE(sat)</sub>	$I_{Cnom} = 30 \text{ A}, T_j = 25 (150) ^{\circ}\text{C}$		1,45 (1,65)	1,85 (2,05)	V			
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 0.43$ mA	5	5,8	6,5	V			
V <sub>CE(TO)</sub>	T <sub>j</sub> = 25 (150) °C		0,9 (0,85)	1 (0,9)	V			
$r_{CE}$	$T_{j} = 25 (150)  ^{\circ}\text{C}$		18 (27)	28 (38)	mΩ			
C <sub>ies</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		1,63		nF			
C <sub>oes</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,11		nF –			
C <sub>res</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,05		nF			
$R_{th(j-s)}$	per IGBT		1,8		K/W			
t <sub>d(on)</sub>	under following conditions		15		ns			
t <sub>r</sub>	$V_{CC} = 300 \text{ V}, V_{GE} = -7/+15$		12		ns			
t <sub>d(off)</sub>	I <sub>Cnom</sub> = 30 A, T <sub>j</sub> = 125 °C		228		ns			
t <sub>f</sub>	$R_{Gon} = R_{Goff} = 12 \Omega$		46		ns			
$E_{on} (E_{off})$	inductive load		0,55 (1,15)		mJ			
Diode - Inverter, chopper								
$V_F = V_{EC}$	I <sub>F</sub> = 30 A, T <sub>i</sub> = 25 (150) °C		1,5 (1,5)	1,7 (1,7)	V			
V <sub>(TO)</sub>	T <sub>i</sub> = 25 (150) °C		1 (0,9)		V			
r <sub>T</sub>	T <sub>j</sub> = 150 () °C		20		mΩ			
$R_{th(j-s)}$	per diode		2,3		K/W			
I <sub>RRM</sub>	under following conditions		19,1		Α			
$Q_{rr}$	$I_{Fnom} = 30 \text{ A}, V_{R} = 300 \text{ V}$		1,8		μC			
E <sub>rr</sub>	$V_{GE} = 0 \text{ V}, T_j = 125^{\circ}\text{C}$		0,53		mJ			
	$di_F/dt = -950 A/\mu s$							
Diode rectifier								
$V_{F}$	I <sub>Fnom</sub> = 25 A, T <sub>i</sub> = 25 °C		1,1		V			
$V_{(TO)}$	T <sub>i</sub> = 150 °C		0,8		V			
r <sub>T</sub>	T <sub>j</sub> = 150 °C		15		mΩ			
$R_{th(j-s)}$	per diode		1,7		K/W			
Temperature Sensor								
R <sub>ts</sub>	5 %, T <sub>r</sub> = 25 (100) °C		5000(493)		Ω			
Mechanical Data								
w			30		g			
$M_s$	Mounting torque	2,25		2,5	Nm			

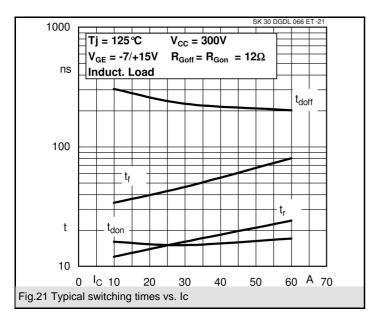


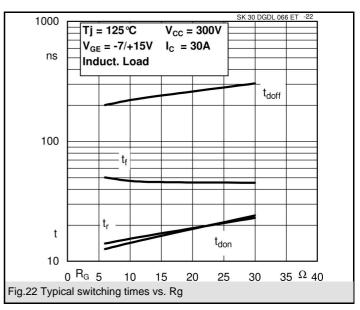


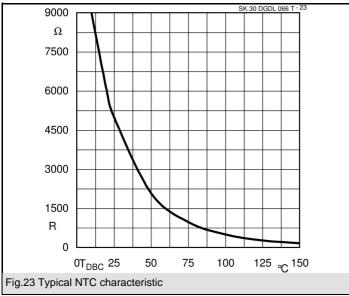


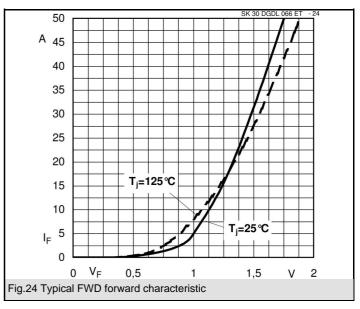


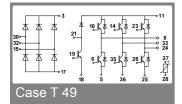


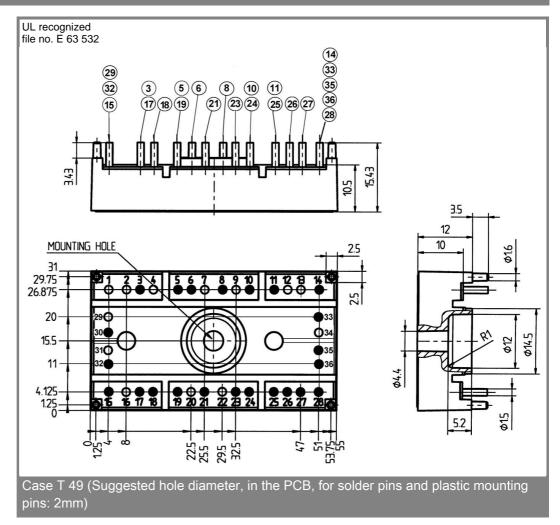












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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